

# **DN030S**

**NPN Silicon Transistor** 

**PIN Connection** 

3

SOT-23F

Base

#### **Features**

- Extremely low collector-to-emitter saturation voltage
  - $(V_{CE(SAT)} = 0.1V \text{ Typ. } @I_{C}/I_{B} = 100\text{mA}/10\text{mA})$
- Suitable for low voltage large current drivers
- Complementary pair with DP030S
- Switching Application

#### **Ordering Information**

Type NO.	Marking	Package Code
DN030S	NO1	SOT-23F

<sup>1)</sup> Device Code 2) Year&Week Code

#### **Absolute maximum ratings**

(Ta=25°C)

Collector

Emitter

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	$V_{CBO}$	15	V
Collector-Emitter voltage	$V_{CEO}$	12	V
Emitter-Base voltage	$V_{EBO}$	5	V
Collector current	I <sub>C</sub>	300	mA
Collector dissipation	P <sub>C</sub>	200	mW
Junction temperature	Tj	150	°C
Storage temperature	$T_{stg}$	-55~150	°C

#### **Electrical Characteristics**

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = 50 \mu A, I_{E} = 0$	15	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	$I_C=1$ mA, $I_B=0$	12	ı	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	$I_E = 50 \mu A, I_C = 0$	5	ı	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 12V, I_{E} = 0$	-	ı	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 5V$ , $I_{C} = 0$	-	-	0.1	μΑ
DC summer main	h <sub>FE1</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	200	-	450	-
DC current gain	h <sub>FE2</sub>	$V_{CE} = 1V, I_{C} = 300 \text{mA}$	70	-	-	-
Collector Emittor saturation voltage	V <sub>CE(sat1)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA	-	ı	0.2	V
Collector-Emitter saturation voltage	V <sub>CE(sat2)</sub>	I <sub>C</sub> =300mA, I <sub>B</sub> =30mA	-	-	0.5	V
Daca Emittar acturation valtage	V <sub>BE(sat1)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA	-	-	1.2	V
Base-Emitter saturation voltage	V <sub>BE(sat2)</sub>	I <sub>C</sub> =300mA, I <sub>B</sub> =30mA	-	-	1.7	V
Transition frequency	f <sub>T</sub>	$V_{CE}=5V$ , $I_{C}=10mA$	-	300	-	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz	-	3	-	PF

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### **Electrical Characteristic Curves**

Fig. 1  $P_C$  -  $T_a$ 

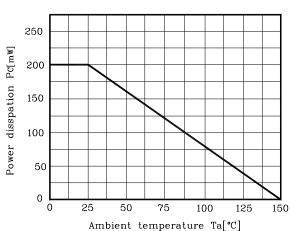


Fig. 2  $I_C$  - $V_{BE}$ 

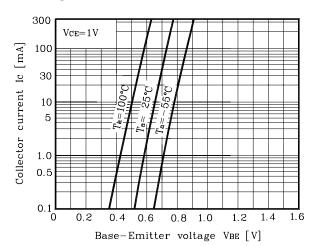


Fig. 3  $h_{FE}\$  -  $\ I_{C}$ 

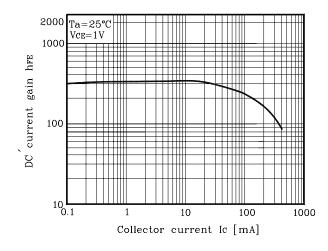


Fig. 4  $I_C$  -  $V_{CE}$ 

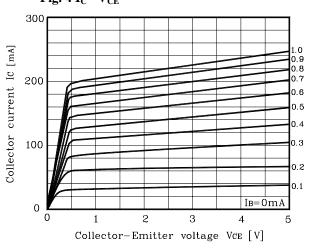
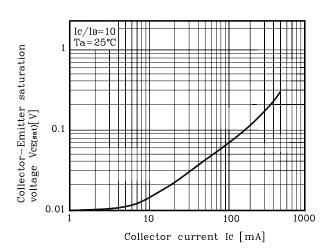
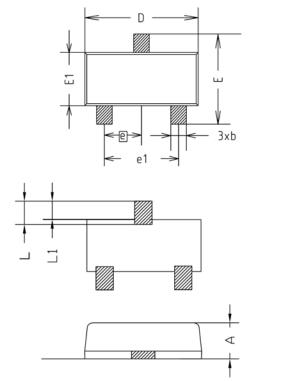


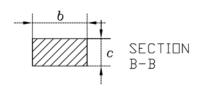
Fig. 5  $V_{\text{CE}(\text{sat})}$  -  $I_{\text{C}}$ 

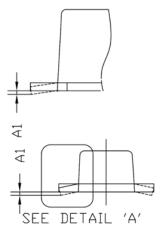


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## **Outline Dimension**



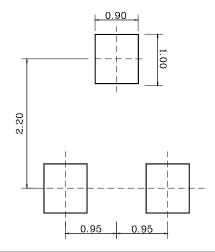




DETAIL 'A'

SYMBOL	1	NOTE			
STINDUC	MINIMUM	NDMINAL	MAXIMUM	NUIL	
Α	0.80	0.90	1.00		
A1	0.00	_	0.10		
b	0.35	0.40	0.45		
C	0.10	0.15	0.20		
D	2.80	2.90	3.00		
Ε	2.30	2.40	2.50		
E1	1.50	1.60	1.70		
е	0.95BSC				
e1	1.80	1.90	2.00		
L	0.48	0.58	0.68		
L1	0.30	-	0.50		

#### \*Recommend PCB solder land [Unit: mm]



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